

# PIN Diode Based Variable Attenuator, 50 - 1000 MHz

Rev. V6

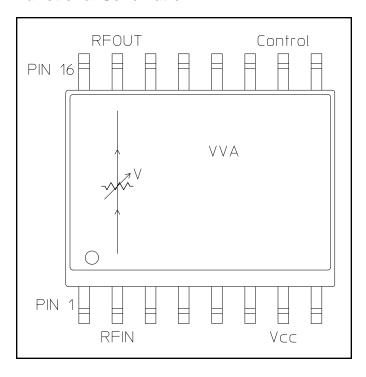
#### **Features**

- High Dynamic Range: 42dB Typical
- Flat Attenuation vs. Frequency
- High P1dB Compression
- Operates on a Single +5V Supply:
- 50 Ohm Nominal Impedance
- SOW-16 Package

## **Description**

M/A-COM's AT10-0019 is a Voltage Controlled PIN diode based  $\pi$  attenuator packaged in a low cost, 16 lead wide body plastic SMT package. The PIN diode design makes this part well suited for applications where low distortion or high linear operating power levels are required. These attenuators are ideal for gain control in multi-channel digital communications systems.

#### **Functional Schematic**



# **Ordering Information**

Part Number	Package
AT10-0019	Bulk Packaging
AT10-0019TR	1000 piece reel
AT10-0019-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

## **Pin Configuration**

Pin No.	Function	Pin No.	Function	
1	GND	9	GND	
2	RF IN	10	V CONTROL	
3	GND	11	GND	
4	GND	12	GND	
5	GND	13	GND	
6	GND	14	GND	
7	V SUPPLY	15	RF OUT	
8	GND	16	GND	

typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

<sup>•</sup> North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400

<sup>•</sup> India Tel: +91.80.4155721 • China Tel: +86.21.2407.1588 Visit www.macomtech.com for additional data sheets and product information.



# PIN Diode Based Variable Attenuator, 50 - 1000 MHz

Rev. V6

# Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50\Omega^1$

Parameter	Test Conditions	Frequency	Units	Min	Тур	Max
Insertion Loss	Vcont.: +10 V	50 - 1000 MHz	dB	_	2.4	2.8
Dynamic Range	Vcont.: 0 V	50 - 1000 MHz	dB	33	42	_
Attenuation Flatness	Attenuation: 0 to 20 dB Attenuation: 20 to 30 dB	50 - 1000 MHz 50 - 1000 MHz	dB dB	_	1.0 1.5	1.5 2.0
VSWR	Vcont.: 0 - 10V	50 - 1000 MHz	Ratio	_	1.7:1	2.1:1
Trise, Tfall Ton, Toff Transients	10%/90%, 90%/10% 50% Cntl to 90%/10% RF In-band	_	μs μs mV		10 15 150	20 25 250
1 dB Compression	Vcont.: 0 - 10V	100 MHz 500 MHz 1000 MHz	dBm dBm dBm	10 17 21	13 20 24	
Input IP <sub>3</sub>	Vcont.: 0 - 10V Two-tone inputs up to +10 dBm	100 MHz 1000 MHz	dBm dBm	24 34	27 37	_
V <sub>CC</sub>	_	_	V	+4.75	+5.0	+5.25
I <sub>cc</sub>	V <sub>CC</sub> = 5.25 V	DC	mA	_	2	2.5
Control Current	_	DC	mA	_	2.7	3.5

<sup>1.</sup> Unit requires external .01 µF DC Blocks on RF lines.

## **Absolute Maximum Ratings <sup>2,3</sup>**

Parameter	Absolute Maximum
Max. Input Power 50 - 500 MHz 500 - 1000 MHz	+24 dBm +30 dBm
Voltages V <sub>CC</sub> Control Voltage	-1 V to +7.0 V -1 V to +15 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

- 2. Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.

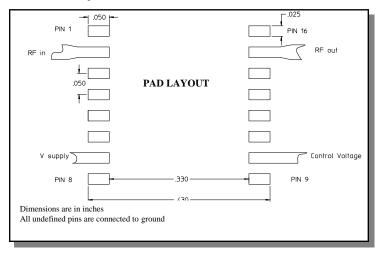
## **Handling Procedures**

Please observe the following precautions to avoid damage:

# Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

### Pad Layout



<sup>•</sup> India Tel: +91.80.4155721 • China Tel: +86.21.2407.1588

Visit www.macomtech.com for additional data sheets and product information.

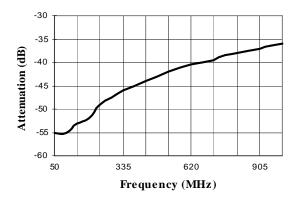


PIN Diode Based Variable Attenuator, 50 - 1000 MHz

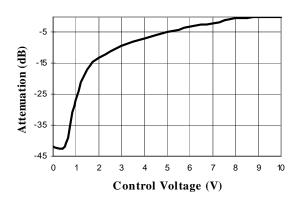
Rev. V6

## **Typical Performance Curves**

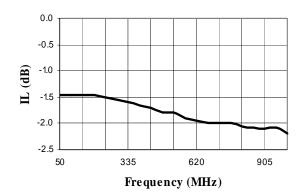
#### Attenuation vs. Frequency @ Control Voltage = 0V



#### Attenuation vs. Control Voltage @ 500 MHz



#### Insertion Loss vs. Frequency @ Control Voltage = 10V



- India Tel: +91.80.4155721
- China Tel: +86.21.2407.1588 Visit www.macomtech.com for additional data sheets and product information.

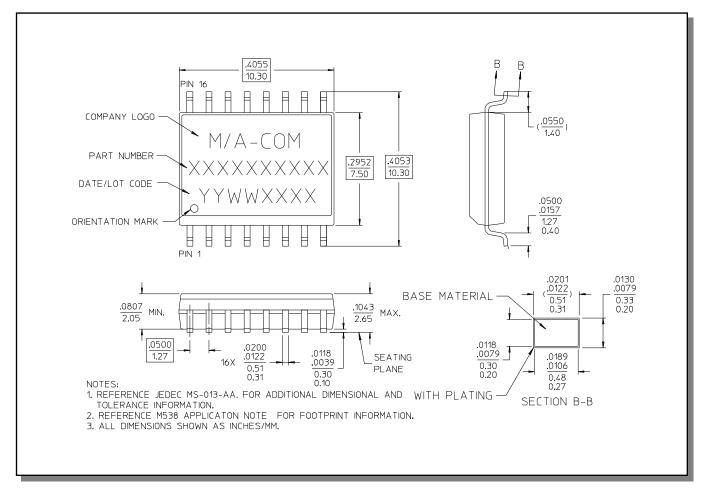
# AT10-0019



PIN Diode Based Variable Attenuator, 50 - 1000 MHz

Rev. V6

## SOW-16<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.